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| <b>INFORMATION DISCLOSURE<br/>STATEMENT BY APPLICANT</b><br><br>(use as many sheets as necessary) |                       | Application Number  | 10/825,123                 |
|   |                       | Filing Date   | 04/16/2004                 |
|   |                       | First Named Inventor  | Morgenshtein               |
|   |                       | Group Art Unit  | <del>4753</del> 4128       |
|   |                       | Examiner Name   | John Ball                  |
| Sheet   | 1                     | Of  | 1                          |
|   |                       | Attorney Docket Number  | 27238                      |
| OTHER PRIOR ART – NON PATENT LITERATURE DOCUMENTS   |                       |   |                            |
| Examiner Initials   | Cite No. <sup>1</sup> | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial symposium, catalog, etc.) date, page(s), volume-issue number(s), publisher, city and/or country where published. | T <sup>2</sup>             |
| /J.C.B./  |                       | Morgenshtein et al, "ISFET Operation in Pass-Transistor Mode without Readout Circuits", Proc. of Euroensors, 17th European Conference on Solid-State Transducers, Portugal, pp. 145-148, Sept. 2003.  |                            |
| ↓   |                       | Morgenshtein et al, "Combined pH-Image Sensor based on Pass-Transistor Operation of ISFET", Proc. of Euroensors, 17th European Conference on Solid-State Transducers, Portugal, pp. 1132-1135, Sept. 2003.  |                            |
|   |                       | Bergveld et al, "Analytical and Biomedical Applications of Non-Selective Field-Effect Transistors", Chap. 8, from "Comprehensive Analytical Chemistry", G. Svehla, Ed., Vol. XXIII, Elsevier, NY,NY, 1988   |                            |
|   |                       | Jakobson, C., "Ion Sensitive Field Effect Transistors in Standard CMOS For Brain Monitoring", Research Thesis, The Technion, Israel, 2001   |                            |
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| Examiner Signature  | /John Ball/           |   | Date Considered 12/12/2007 |

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